



Data Sheet

IC RF AMP VSAT 0HZ-30GHZ DIE

Manufacturers Analog Devices, Inc

Package/Case QFN32

Product Type RF Amplifiers

RoHS Pb-free Halide free

Please submit RFQ for HMC994A or Email to us: sales@ovaga.com We will contact you in 12 hours.



Images are for reference only

RFO

General Description

Lifecycle

The HMC994A is a GaAs MMIC pHEMT DistributedPower Amplifier which operates between DCand 30 GHz. The amplifier provides 14 dB of gain,+39 dBm output IP3 and +28 dBm of output power at1 dB gain compression while requiring 250 mA from a+10 V supply. The HMC994A exhibits a slightlypositive gain slope from 2 to 20 GHz, making it idealfor EW, ECM, Radar and test equipment applications. With up to 39 dBm Output IP3 the HMC994Ais ideal for high linearity applications in military and space as well as test equipment where high ordermodulations are used. The HMC994A amplifier I/Osare internally matched to 50 Ohms facilitating integrationinto Multi-Chip-Modules (MCMs). All datais taken with the chip connected via two 0.025 mm(1 mil) wire bonds of minimal length 0.31 mm (12 mils).

Features	Application
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High P1dB Output Power: 28 dBm

Test Instrumentation

High Psat Output Power: 30 dBm Military & Space

High Gain: 14 dB Fiber Optics

High Output IP3: 39 dBm

Supply Voltage: +10 V @ 250 mA

50 Ohm Matched Input/Output

Die Size: 2.75 x 1.45 x 0.1 mm

Related Products



HMC3653LP3BE
Analog Devices, Inc
QFN-12



Analog Devices, Inc QFN-16

HMC441LP3E



HMC253AQS24

Analog Devices, Inc

24-SSOP (0.154, 3.90mm Width)



HMC358MS8GE Analog Devices, Inc MSOP-8



HMC453ST89E
Analog Devices, Inc
ST89E



Analog Devices, Inc LP3

HMC948LP3E



HMC490
Analog Devices, Inc
SMD



Analog Devices, Inc QFN-16

HMC618ALP3E